



SANYO Semiconductors

DATA SHEET

LA1135

LA1135M

Monolithic Linear IC

For Car Radios and Home Stereos
AM Tuner System

Overview

The LA1135 and LA1135M are high-performance AM electronic tuner IC that is greatly improved in cross modulation characteristics. It is especially suited for use in car radio and home stereo (antenna : loop) applications.

Features

- Excellent cross modulation characteristics : Meets the requirements for preventing not only adjacent-channel interference but also interference caused by all channels within broadcast band.
- Narrow-band signal meter output : Usable as auto search stop signal. Has linearity up to 80dB μ .
- Local oscillation buffer output : Facilitates designing of electronic tuner system, frequency display, etc.
- OSC (with ALC) : Improves tracking error because oscillation output is stabilized at a low level (380mVrms) for varactor diode.
- MIX : Double-balanced differential MIX meeting the requirements for preventing spurious interference, IF interference.
- Good characteristics at high input : 130dB μ input, $f_m = 400\text{Hz}$ 80% mod THD = 0.4% typ
- Low noise : Good S/N at medium input (56dB typ)
- Usable sensitivity : (S/N = 20dB input) : 25dB μ (2SK315 I_{DSS} = 11mA)
- VCC variation compensation : Less variation in gain, distortion : 8 to 12V
- Reduced pop noise : Capable of reducing pop noise at the time of VCC ON, mode select by adjusting AGC time constant.

Functions

- MIX
- IF amplifier
- AGC (normal)
- Auto search stop signal (signal meter output)
- Others
- OSC (with ALC)
- Detector
- RF wide-band AGC
- Local oscillation buffer output

■ Any and all SANYO Semiconductor Co.,Ltd. products described or contained herein are, with regard to "standard application" intended for the use as general electronics equipment (home appliances, AV equipment, communication device, office equipment, industrial equipment etc.). The products mentioned herein shall not be intended for use for any "special application" (medical equipment whose purpose is to sustain life, aerospace instrument, nuclear control device, burning appliances, transportation machine, traffic signal system, safety equipment, etc.) that shall require extremely high level of reliability and can directly threaten human lives in case of failure or malfunction of the product or may cause harm to human bodies, nor shall they grant any guarantee thereof. If you should intend to use our products for applications outside the standard applications of our customer who is considering such use and/or outside the scope of our intended standard applications, please consult with us prior to the intended use. If there is no consultation or inquiry before the intended use, our customer shall be solely responsible for the use.

■ Specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.

SANYO Semiconductor Co., Ltd.

www.semiconductor-sanyo.com/network

LA1135, 1135M

Specifications

Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	unit
Maximum supply voltage	V _{CC} max	Pins 8, 14	16	V
Output voltage	V _O	Pins 7, 10	24	V
Input voltage	V _{IN}	Pin 6	5.6	V
Current drain	I _{CC}	Pins 7 + 8 + 10 + 14	41	mA
Flow-out current	I ₁₈	Pin 18	2	mA
	I ₂₀	Pin 20	2	mA
Allowable power dissipation	Pd max	LA1135	730	mW
		LA1135M Ta ≤ 60°C, with PCB*	660	mW
Operating temperature	Topr	LA1135	-20 to +70	°C
		LA1135M	-40 to +80	°C
Storage temperature	Tstg		-40 to +125	°C

*PCB : 54mm × 34mm × 1.7mm, glass epoxy board.

Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	unit
Recommended supply voltage	V _{CC}		8	V
Operating supply voltage range	V _{CC} op		7.5 to 12	V

Electrical Characteristics at Ta = 25°C, V_{CC} = 8V, f_r = 1MHz, f_m = 400Hz, See specified test circuit.

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Current drain	I _{CC1}	Quiescent	13.5	22.5	32.5	mA
	I _{CC2}	130dBμ input	20.0	30.0	41.0	mA
Detection output	V _{O1}	16dBμ input, 30% mod	-29.0	-25.0	-21.0	dBm
	V _{O2}	74dBμ input, 30% mod	-15.0	-12.0	-9.0	dBm
Signal-to-noise ratio	S/N	74dBμ input, 30% mod	51.0	56.0		dB
Total harmonic distortion	THD1	74dBμ input, 30% mod		0.3	1.0	%
	THD2	74dBμ input, 80% mod		0.3	1.0	%
	THD3	130dBμ input, 80% mod		0.4	2.0	%
Signal meter output	V _{SM1}	Quiescent		0	0.3	V
	V _{SM2}	130dBμ input	3.5	5.0	7.5	V
Input at signal meter output 1V	V _{IN1}	V _{SM} = 1V	18.0	24.0	30.0	dBμ
Local oscillation buffer output	V _O SC BUF		320	380		mVrms

Reference Characteristics

Parameter	Symbol	Conditions	Ratings	Unit
			typ	
Usable sensitivity	Q.S.	Input at S/N = 20dB (2SK315 I _{DDS} = 11mA)	25.0	dBμ
Wide-band AGC ON-state input		Reception 1.0 MHz quiescent Interference 1.4 MHz non-mod at input for AMT.D. ON	82.0	dBμ
Detection output variation	ΔV _O	Input 74dBμ → 130dBμ	0.2	dB
Local oscillation variation within broadcast band	ΔV _O SC	V _O SC L - V _O SC H	15	mVrms
Signal meter band *	V _{SM} -BW1	74dBμ input, frequency at which output is reduced to 1/2	±1.5	kHz
	V _{SM} -BW2	74dBμ input, frequency at which output is reduced to 1/10	-4.5/+7	kHz
Selectivity		30% mod ±10kHz *	43	dB
IF interference	IF. R.	f _r = 600kHz *	77.5	dB
Image frequency interference	IM. R.	f _r = 1400kHz *	52.0 (63.0)	dB

Note : * : Wide-band AGC OFF

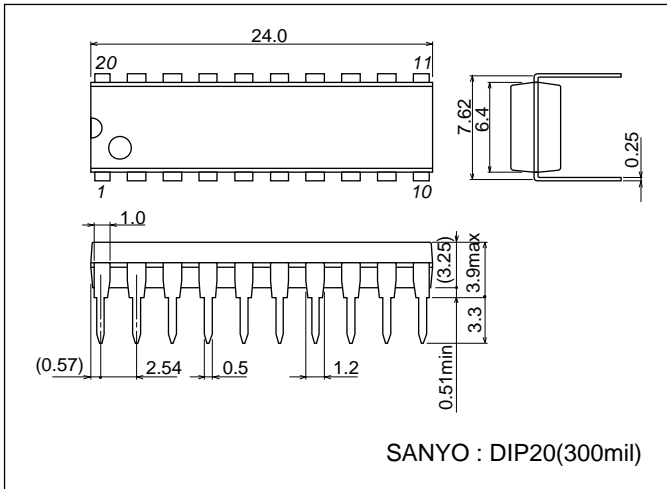
() : See circuit on page 7.

LA1135, 1135M

Package Dimensions

unit : mm
3021C

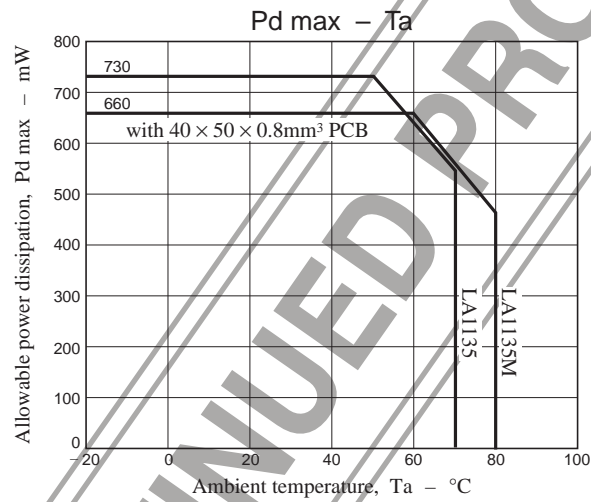
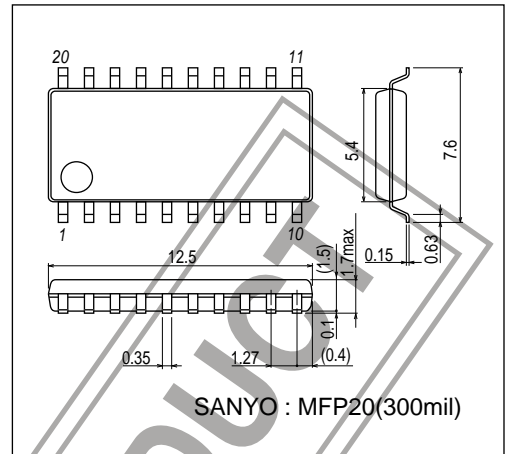
[LA1135]



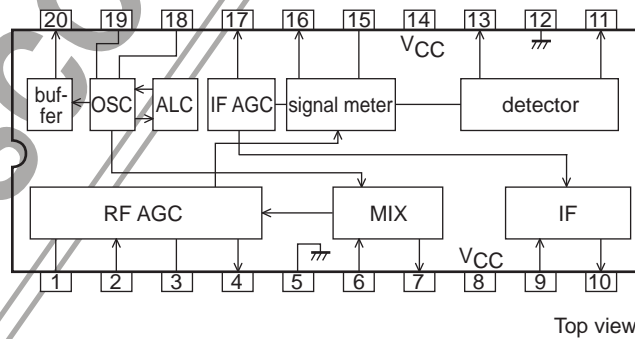
Package Dimensions

unit : mm
3036C

[LA1135M]



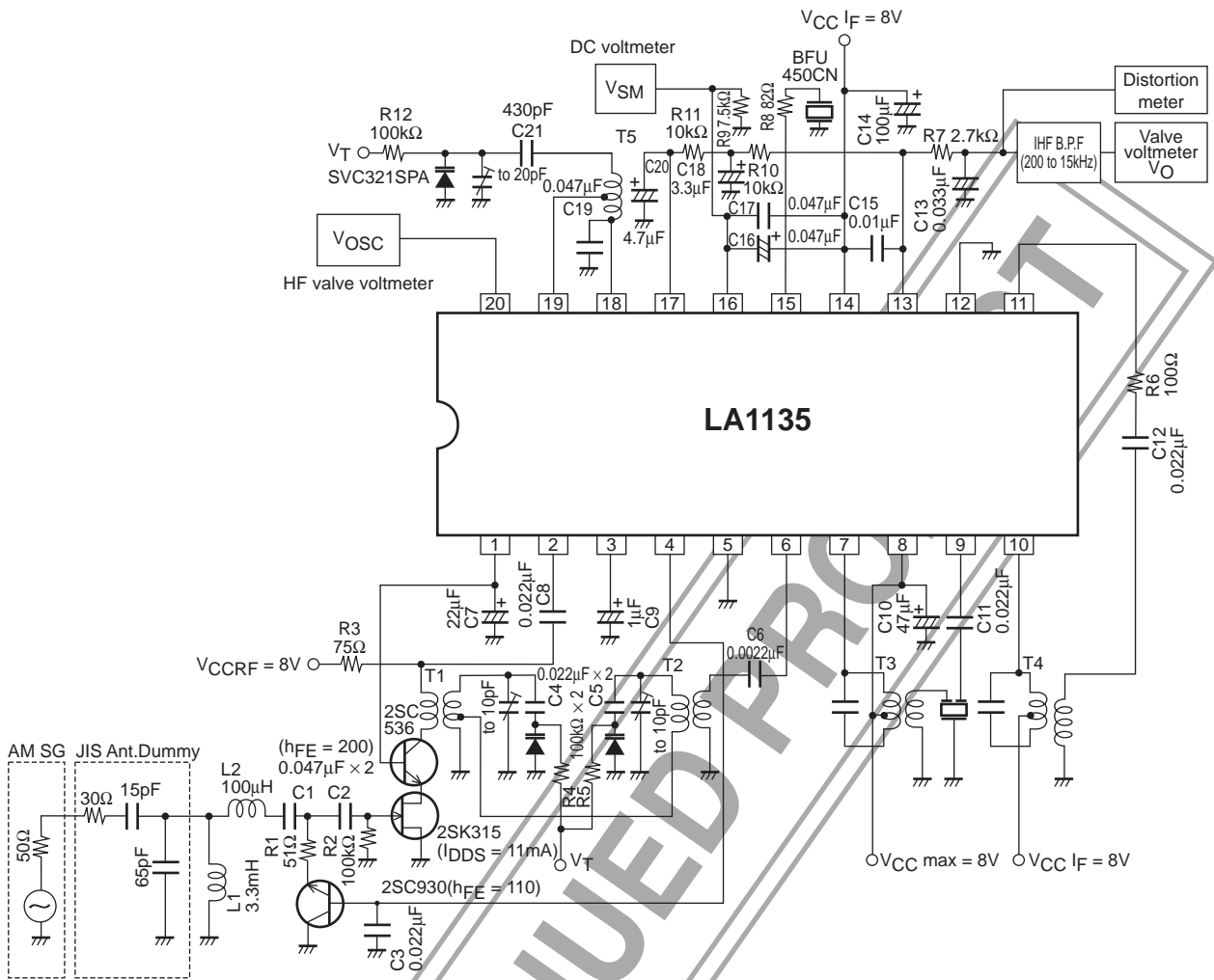
Block Diagram



LA1135, 1135M

Test Circuit 1

$V_{CC} = 8V$, $f_r = 1MHz$, $f_m = 400Hz$

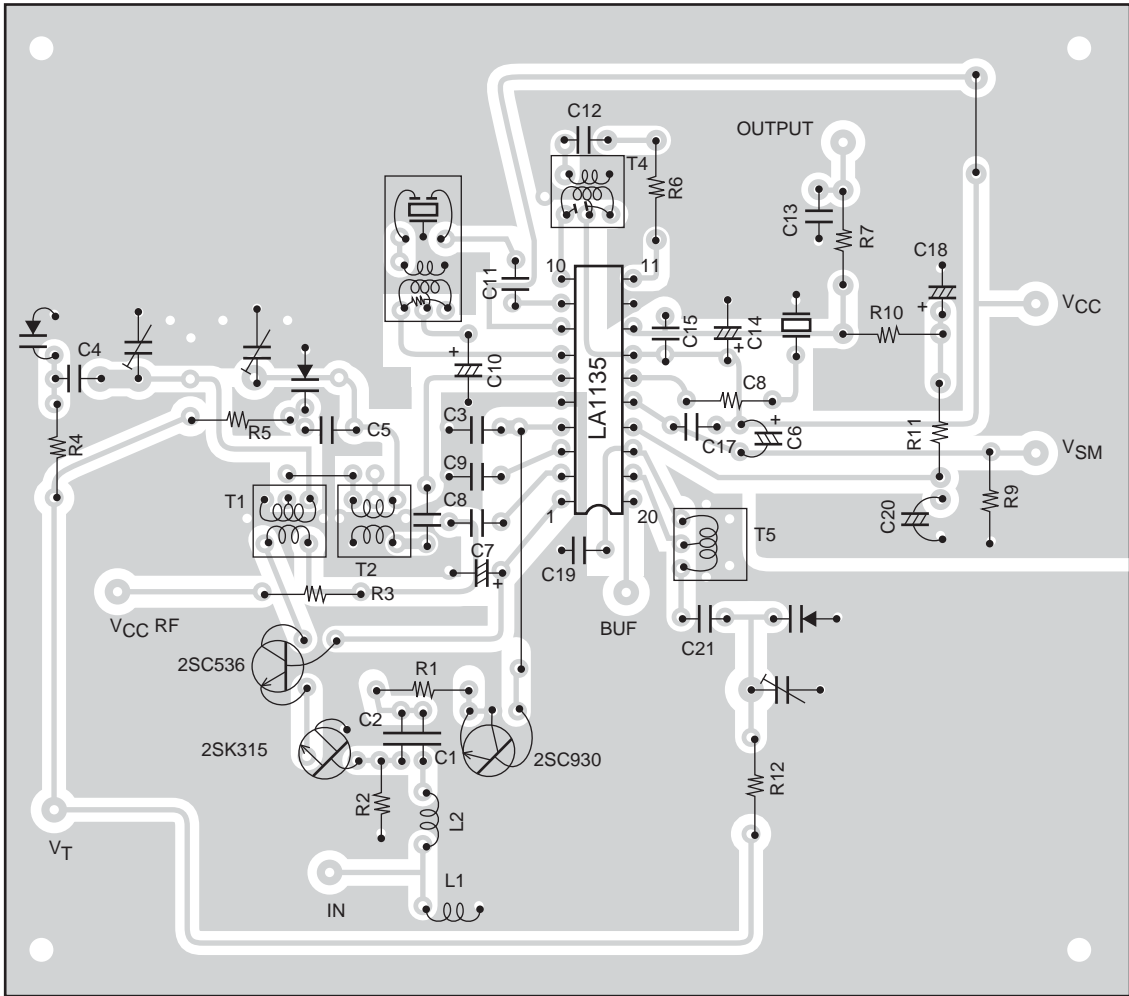


Varactor diode	SVC321	(Sanyo)
Narrow-band filter	BFU450CN	(Murata)

Coil		
T1	YT-30020	(Mitsumi)
T2	YT-30018	(Mitsumi)
T3	CFMA-027	(Toko)
T4	YT-30007	(Mitsumi)
T5	YT-30008	(Mitsumi)

LA1135, 1135M

Sample Printed Circuit Pattern



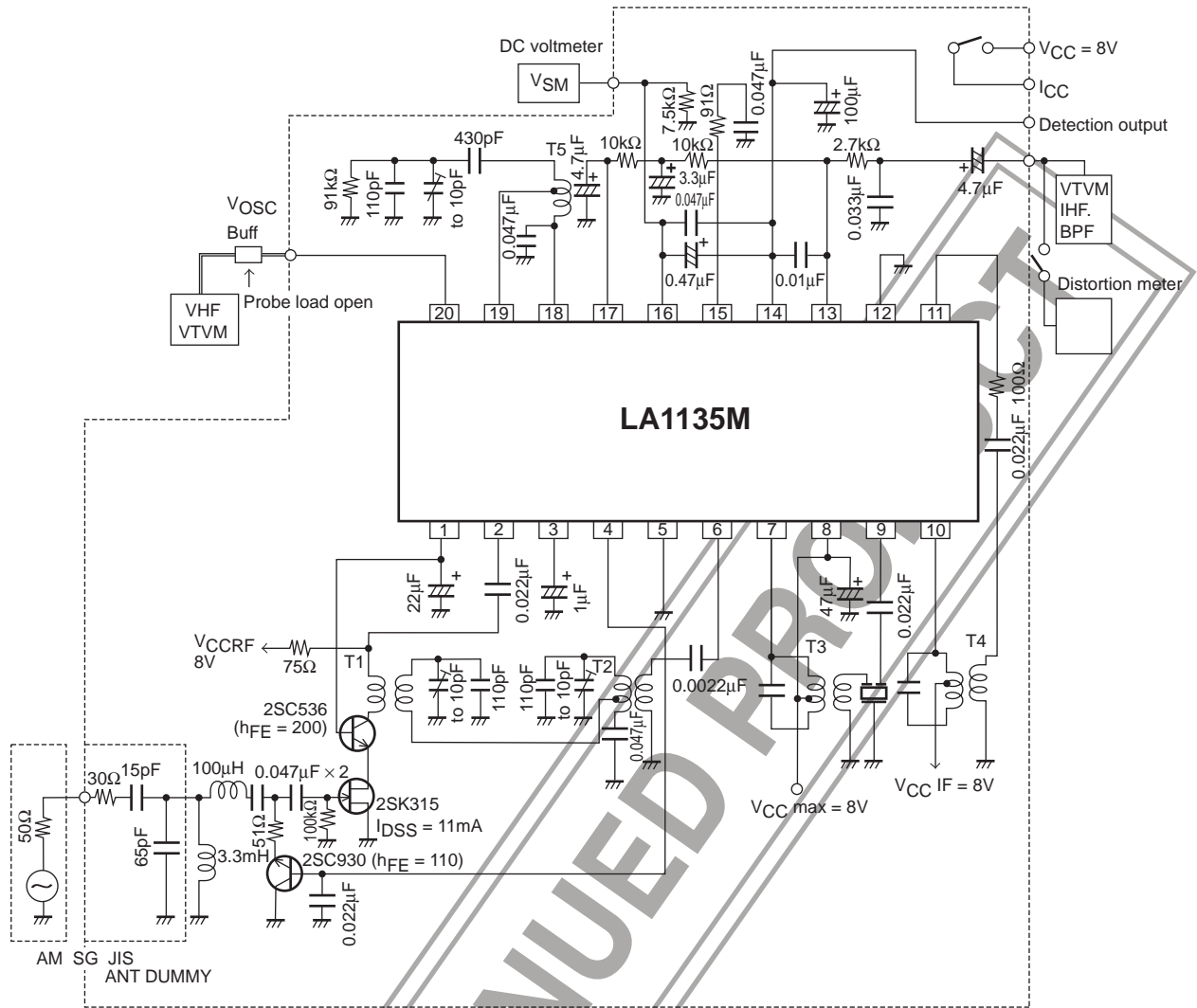
Cu-foiled area $105 \times 120\text{mm}^2$

DISCONTINUED

LA1135, 1135M

Test Circuit 2

$V_{CC} = 8V$, $f_r = 1MHz$, $f_m = 400Hz$



Coil		
T1	YT-30202	(Mitsumi)
T2	YT-30018	(Mitsumi)
T3	CFMA-021A	(Toko)
T4	YT-30007	(Mitsumi)
T5	YT-30008	(Mitsumi)

Varactor diode	SVC321	(Sanyo)
Narrow-band filter	BFU450CN	(Murata)

DISCONTINUED

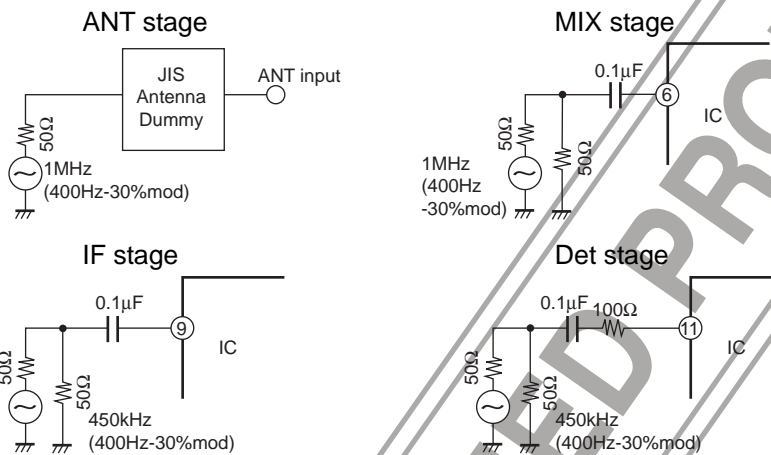
Proper cares in using IC

1. Bias condition : $RF V_{CC} \leq IF V_{CC}$
2. Avoid coupling between the antenna tuning circuit and the local oscillation.
3. Connect detection capacitor C15 across pins 13 (output) and 14 (V_{CC}) so that no leakage of the IF signal to the GND line occurs. (If connected to GND, the tweet and the usable sensitivity may get worse.) Radiation from C15 may cause harmonics in the IF signal to return to the RF stage, thereby leading to more tweet interference. So, connect C15 as close to pins 13, 14 as possible. Consider the direction of the capacitor and separate it from the ANT circuit.
4. For R9, use a semifixed resistor with V_{SM} considered.
5. When designing the coils, consider the following conditions.

Shown below is the input level at each pin at which the detection output at $f_m = 400\text{Hz } 30\% \text{ mod}$ becomes -25dB .

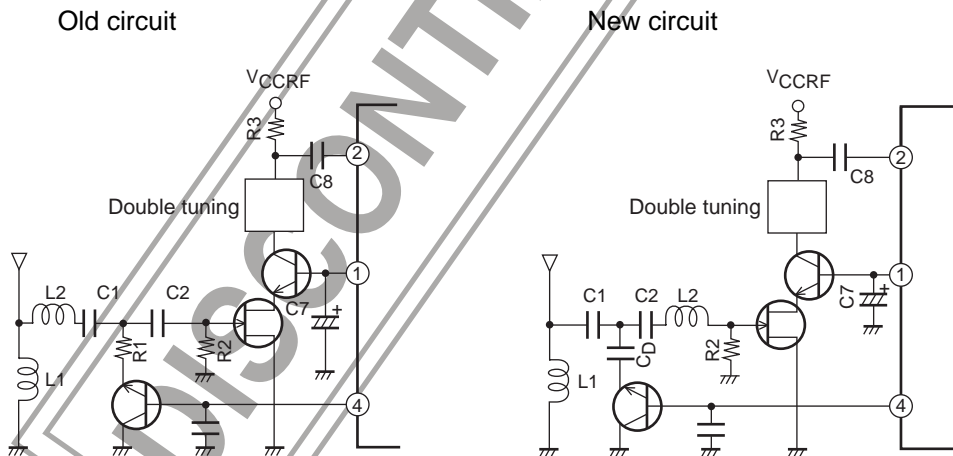
ANT	MIX	IF	Det
16.0dB μ	28.0dB μ	45.0dB μ	61.0dB μ

How to apply input to each stage



6. ANT damping

To make the ANT damping constant within the receiving band, change the application circuit as shown below.



Measures

- Replace R1 with C_D .
- C_D (2000pF to 3000pF or thereabouts)
- Relocate L2.
- Damping (600kHz to 1400kHz) Old circuit -15dB
- New circuit -4dB

7. Meaning of L2

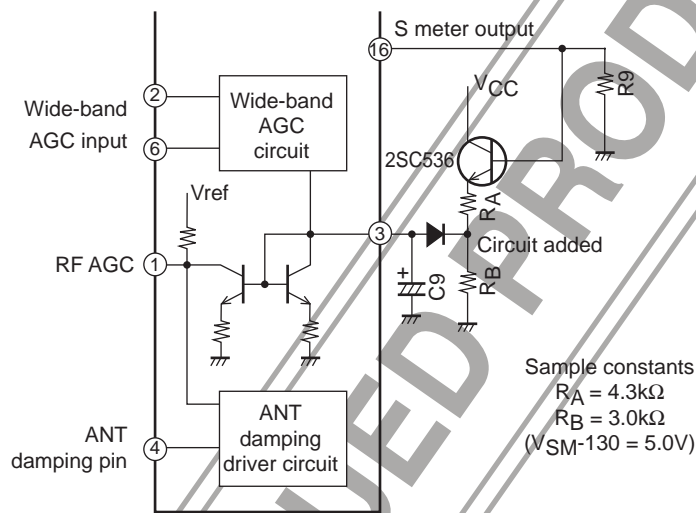
If the RF stage is double-tuned, the difference in sensitivity within the RF band almost disappears, but an antiresonance point of approximately 20MHz appears, thereby leading to worse spurious characteristics. So, L2 is used to remove the SW band.

8. Wide-band AGC

This IC contains 2-channel wide-band AGC. Pin 6 detects an undesired signal within the RF band and wide-band AGC is applied. This detection sensitivity is determined inside the IC. Pin 2 detects an undesired signal outside the RF band. This detection sensitivity is determined by R3. When 1mVrms (f = 1MHz) signal is applied to pin 2, AGC operates.

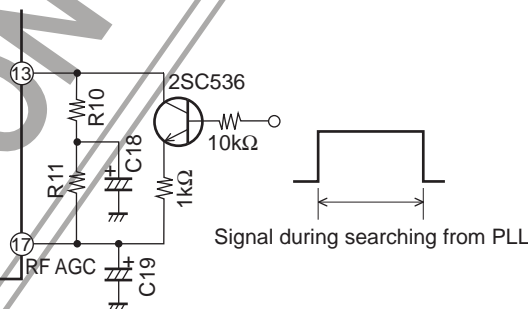
9. Measures against suppression of sensitivity

In the AGC circuit of the test circuit the presence of an undesired signal of high strength within the receiving band may cause the desired signal to be suppressed when the desired signal is low or medium in strength. Shown below is the circuit configuration where the necessary measures are taken against this suppression.



10. Transient response of S meter output at search, stop mode

The circuit configuration shown below is available to stabilize the transient response of the S meter output at the search, stop mode.



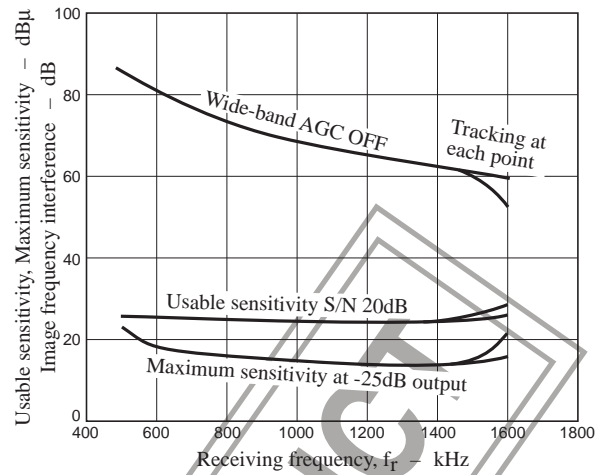
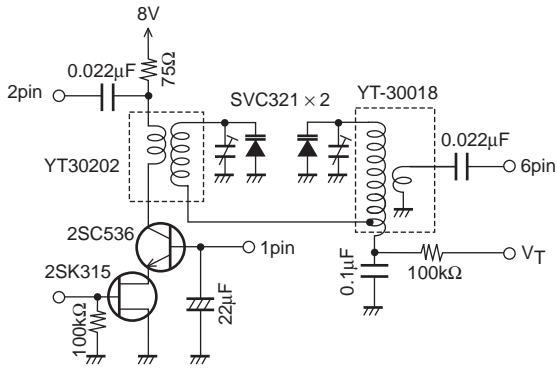
11. When using LW (approximately 50°C or greater), additionally connect a resistor of 27kΩ across pins 18 and 19 against increase in local oscillation level. When using MW, no additional resistor is required.

12. Improvement in image frequency interference

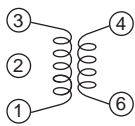
Change the RF double-tuning coil as follows, and the image frequency interference becomes 63dB at $f_i = 1400kHz$. (Q of the tuning circuit must not be decreased with resistor 100kΩ.)

Continued on next page.

Continued from preceding page.

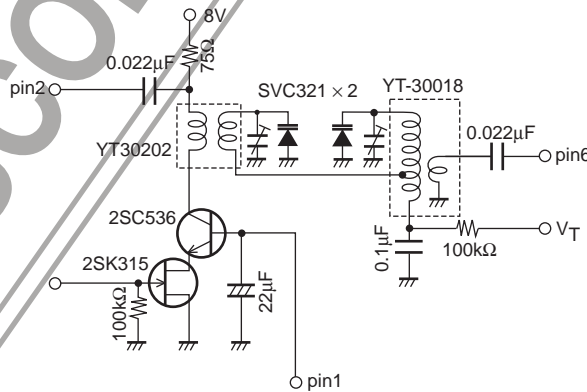


Specification for coil



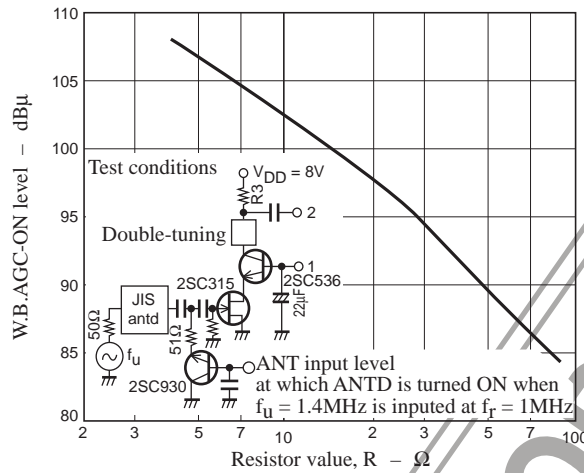
	YT-30202 (Mitsumi)	2157-2239-649 (Sumida)
1-3	84T	7BRS-9286A (Toko)
4-6	17T	

13. The variations (especially in case of small coupling coefficient) in the oscillation coil may cause a parasitic oscillation of approximately 100MHz to occur at the local oscillation buffer output (pin 20) at low temperatures. In this case, connect a capacitor of 30pF or greater across pin 20 and GND. (When the oscillation coil is used with no tap, no problem arises.)
14. The recommended double-tuning circuit has a loose coupling at 2T. Therefore, the change in the total number of turns may affect the coupling coefficient subtly, causing a tight coupling and making the selectivity characteristic double-humped. Especially for a receiving band of 1400kHz or more, the tracking method may affect the band characteristic of sensitivity and the cross modulation characteristic considerably. When making a design, check to see if critical coupling occurs or not.
15. Sensitivity difference at 600kHz or less
 In the application circuit configuration shown below, the bypass capacitor in the position where the tuning voltage is applied and coupling L for double-tuning may cause an antiresonance point of 400kHz to 600kHz depending on the variations in the coil, varactor diode, etc. The value of the bypass must be 0.047μF or greater. The recommended value is 0.1μF.

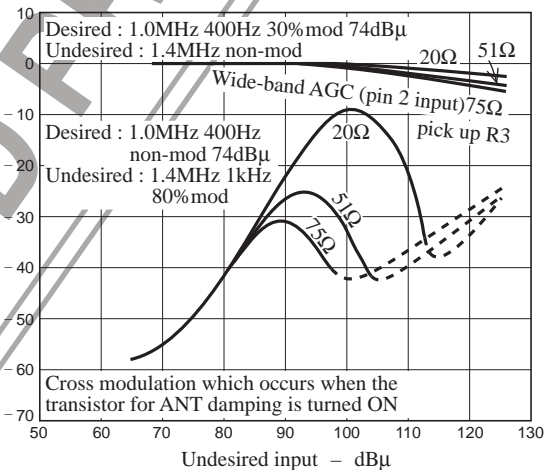
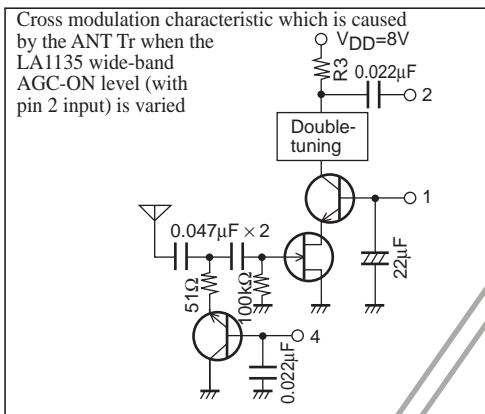


16. Measure against suppression of sensitivity in the presence of an undesired signal of high strength (Sample application where two PIN diodes are used in the antenna damping circuit)

The LA1135 contains the wide-band AGC circuit (wide-band AGC with pin 2 input) against cross modulation which occurs because an undesired signal of high strength distorts the FET input. The AGC = ON level depends on the value of external resistor R3 as shown below.



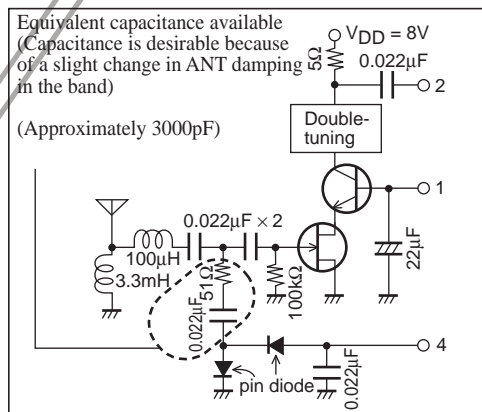
When a nonlinear element, such as transistor, is used for antenna damping, cross modulation which occurs when the transistor is turned ON is as shown below.



The dynamic range of the FET input covers up to approximately 110dBμ of antenna input, but the AGC-ON level must be set lower because of the bad effect shown above.

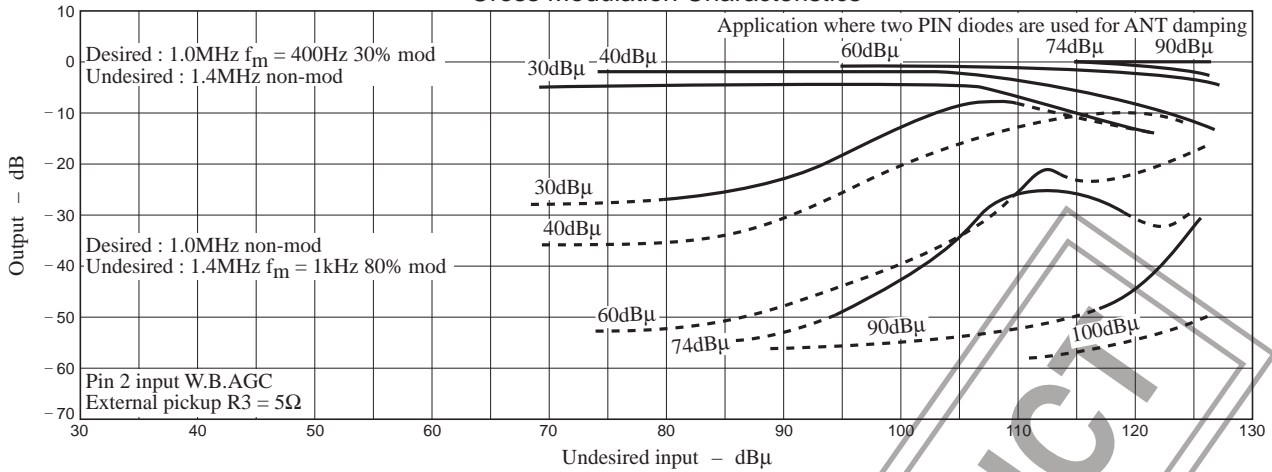
Therefore, there are some cases where it is difficult to receive a desired signal of low strength in the presence of an undesired signal of high strength. To solve this problem, a sample application circuit where two PIN diodes with good linearity are used for antenna damping and its cross modulation characteristic are shown below.

Sample Application Circuit where two PIN diodes are used for ANT damping



LA1135, 1135M

Cross Modulation Characteristics

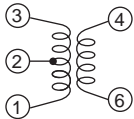


17. For details of the LA1135 wide-band AGC, refer to Technical Data No.79.

External Parts

(1) RF double-tuning coil

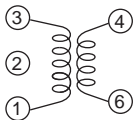
Primary



	YT-30020 (Mitsumi)	2157-2239-518A (Sumida)	7BRS-8934A (Toko)
1-2	2T	2T	2T
6-4	37T	40T	35T
2-3	82T	90T	75T

L1-3 = 224μH

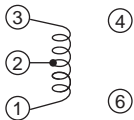
Secondary



	YT-30018 (Mitsumi)	2157-2239-517A (Sumida)	7BRS-8932A (Toko)
1-2	2T	2T	2T
6-4	15T	16T	14T
2-3	82T	90T	75T

L1-3 = 224μH

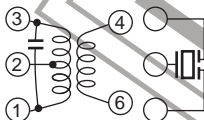
(2) OSC coil



	YT-30008 (Mitsumi)	2157-2239-516 (Sumida)	7BRS-5941Y (Toko)
1-2	29T	34T	29T
2-3	29T	35T	29T

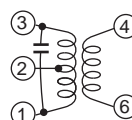
L1-3 = 118μH

(3) IFT (I)



	CFMA-027 (Toko)
1-2	69T
2-3	77T
4-6	14T
Center frequency 450kHz	
Qu = 115 ± 20%	
Tuning capacitance 180pF	

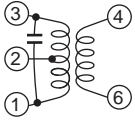
High selectivity type



	YT-30042 (Mitsumi) +SFP450H (Murata)
1-2	49T
4-6	27T
2-3	103T
Center frequency 450kHz	
Qu = 45 ± 20%	
Tuning capacitance 180pF	

LA1135, 1135M

(4) IFT (II)



	YT-30007 (Mitsumi)	4140-1289-164 (Sumida)	7MC-6272N (Toko)
1-2	115T	111T	110T
4-6	6T	6T	6T
2-3	37T	36T	36T
	Center frequency 455kHz, Qu = 110% Tuning capacitance 180pF	Center frequency 455kHz, Qu = 110% Tuning capacitance 180pF	Center frequency 455kHz, Qu = 110% Tuning capacitance 180pF

(5) Varactor diode : SVC321

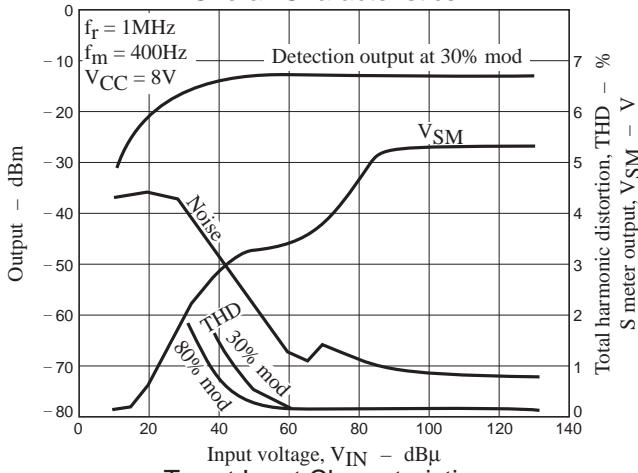
(6) FET at RF stage : 2SK315 F, G
2SK427 T, U

(7) Transistor for AGC
FET AGC : 2SC536 F, G
ANT damping : 2SC930 E

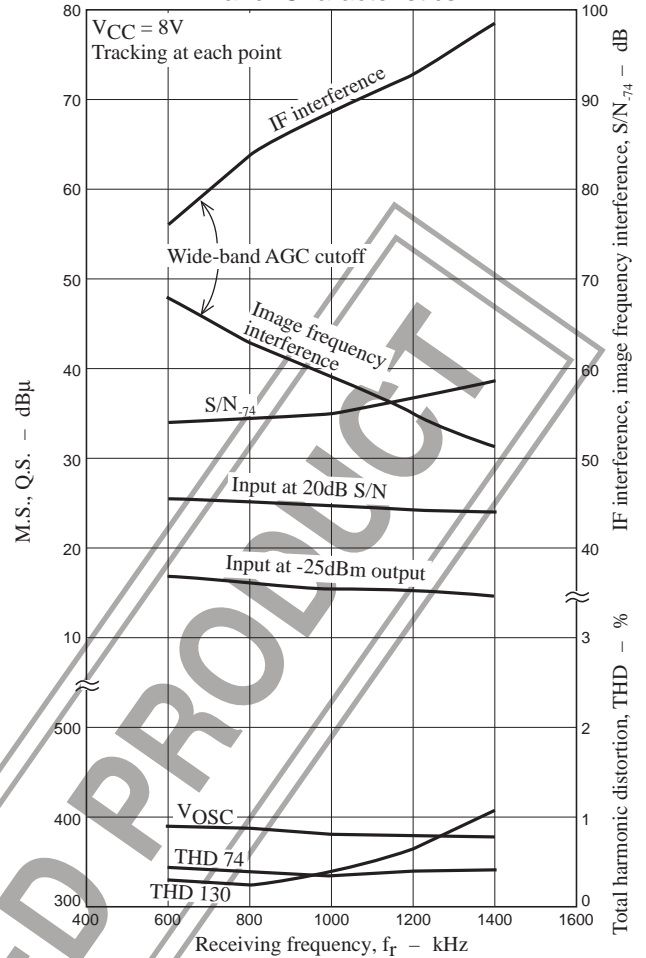
(8) Narrow-band resonator BFU450CN Murata

DISCONTINUED PRODUCT

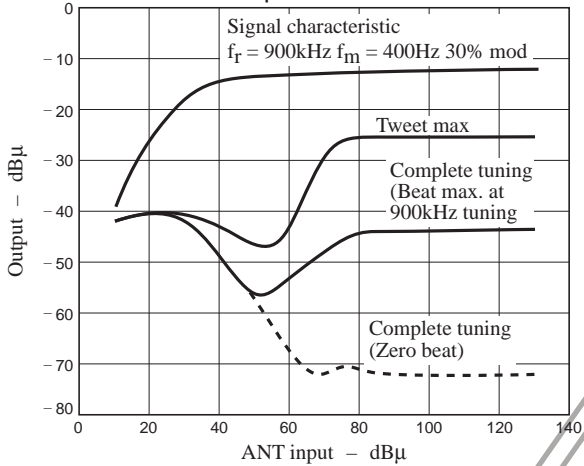
Overall Characteristics



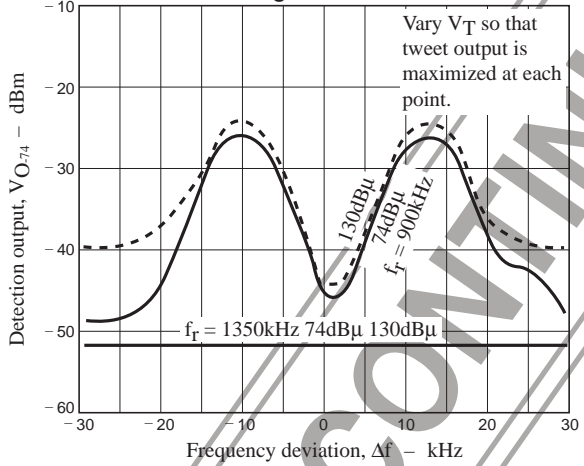
Band Characteristics



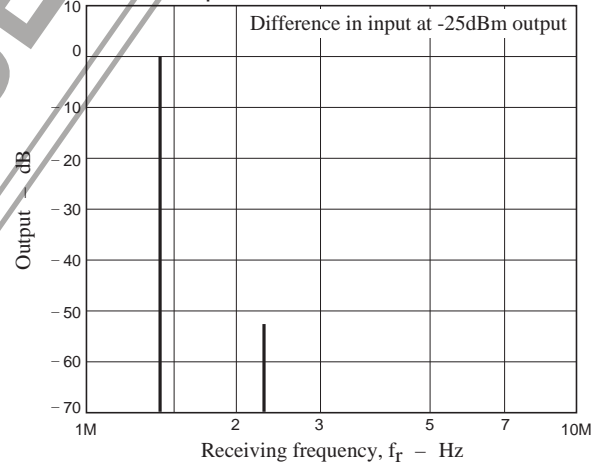
Tweet Input Characteristics



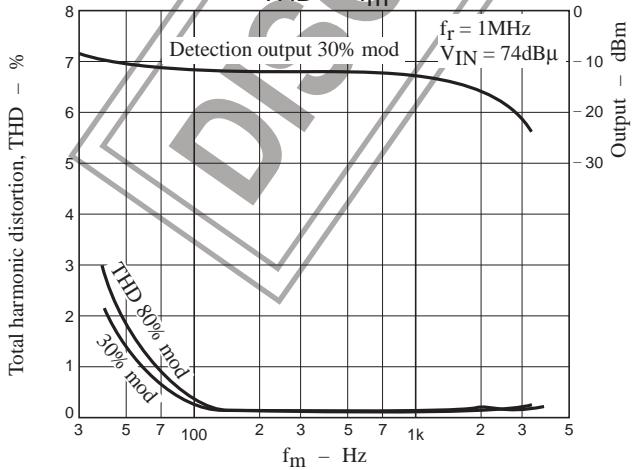
Detuning Characteristics



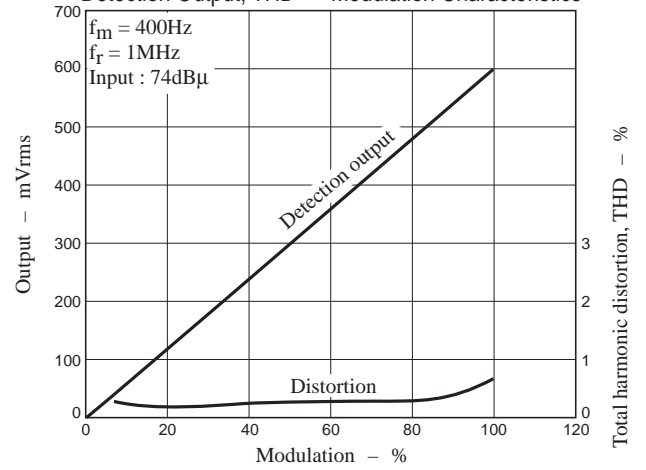
Spurious Characteristics

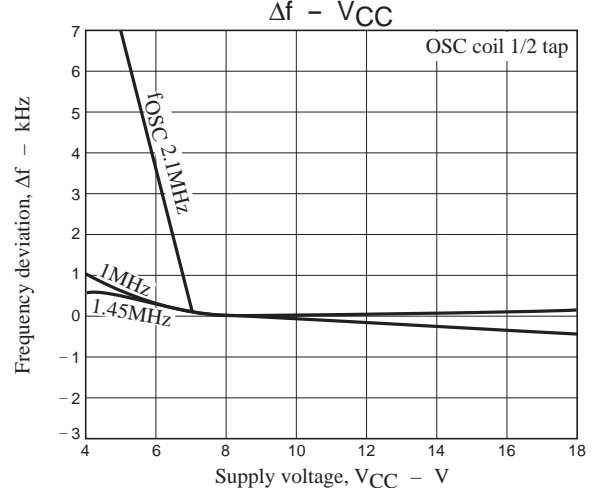
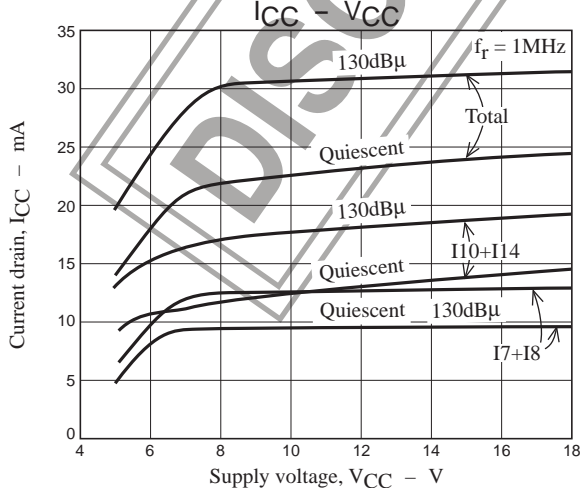
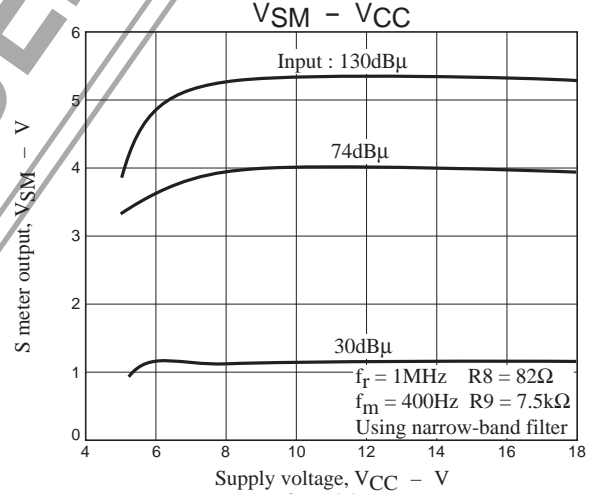
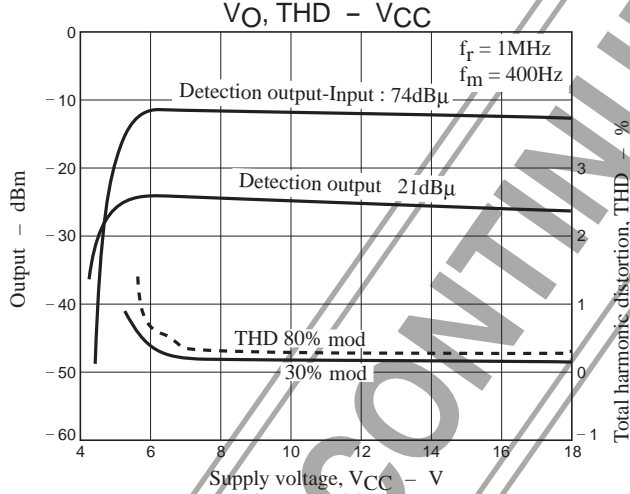
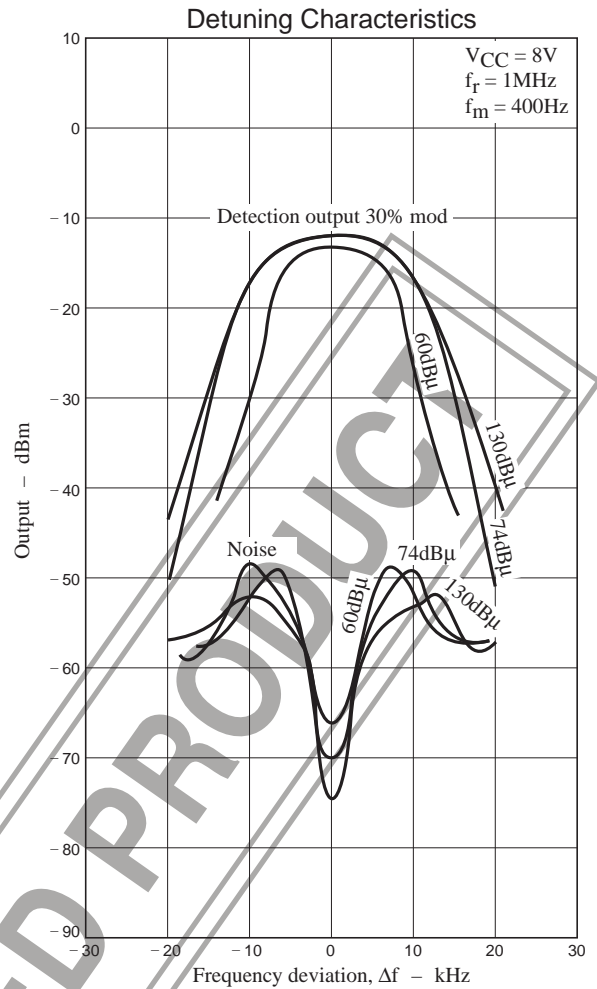
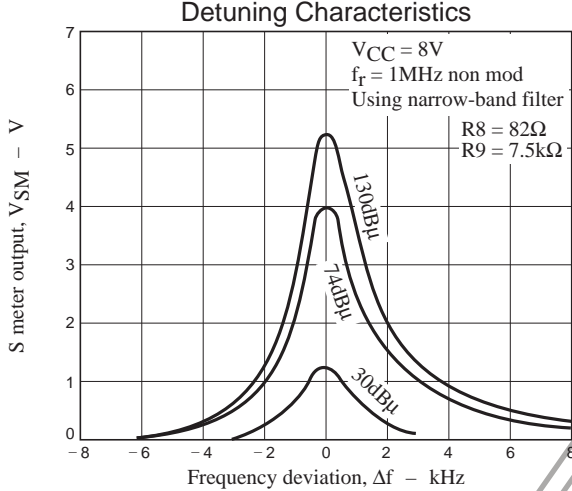
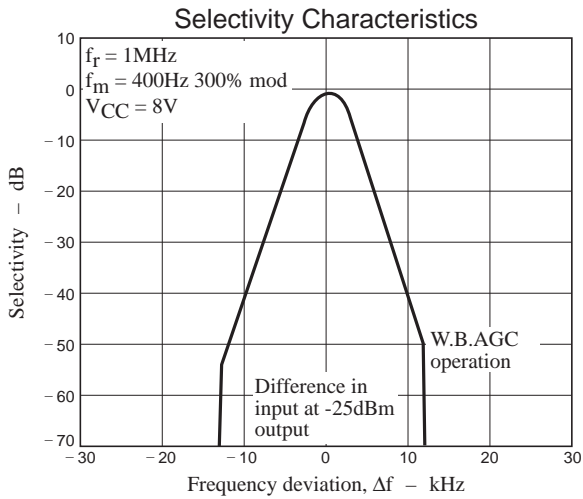


THD - f_m

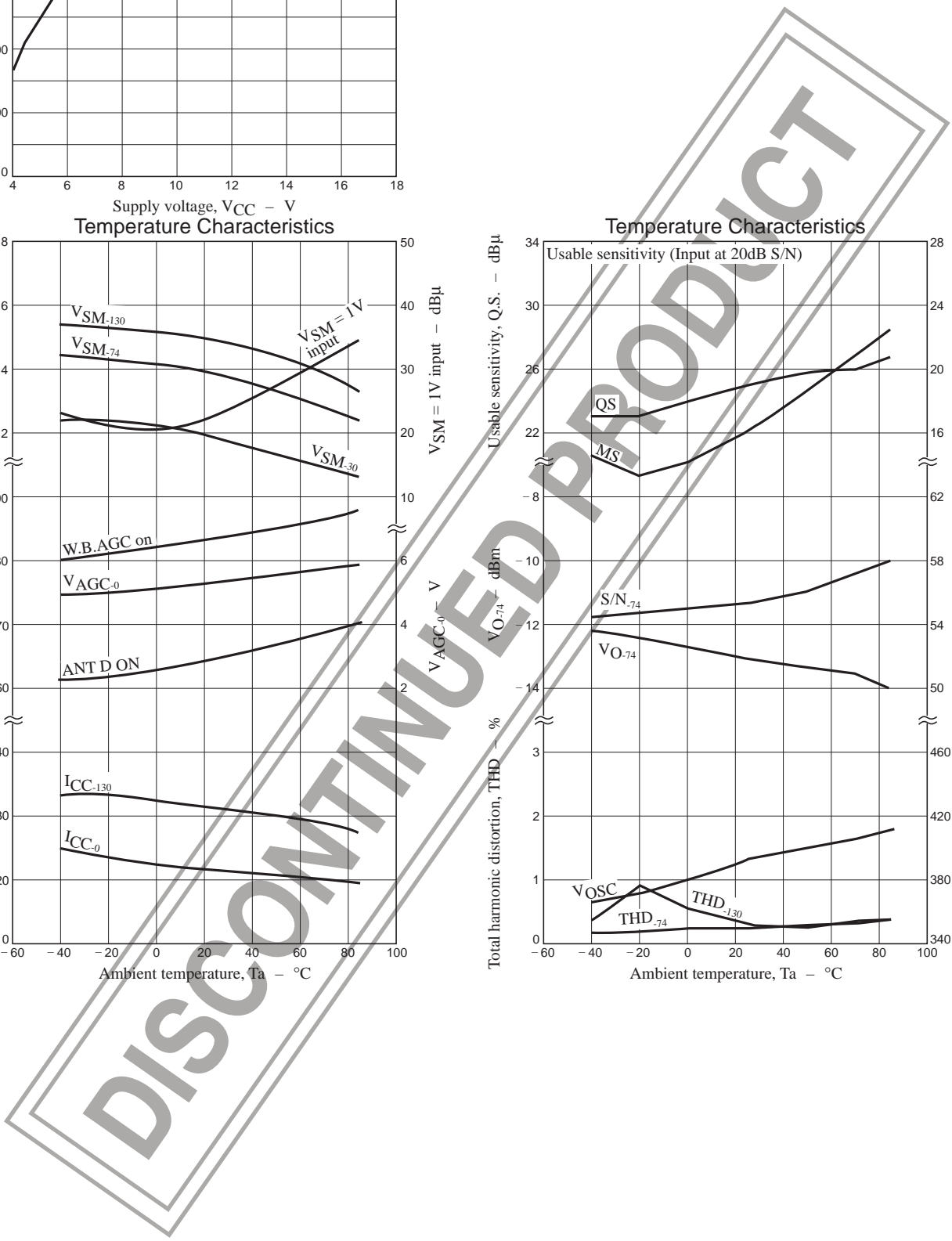
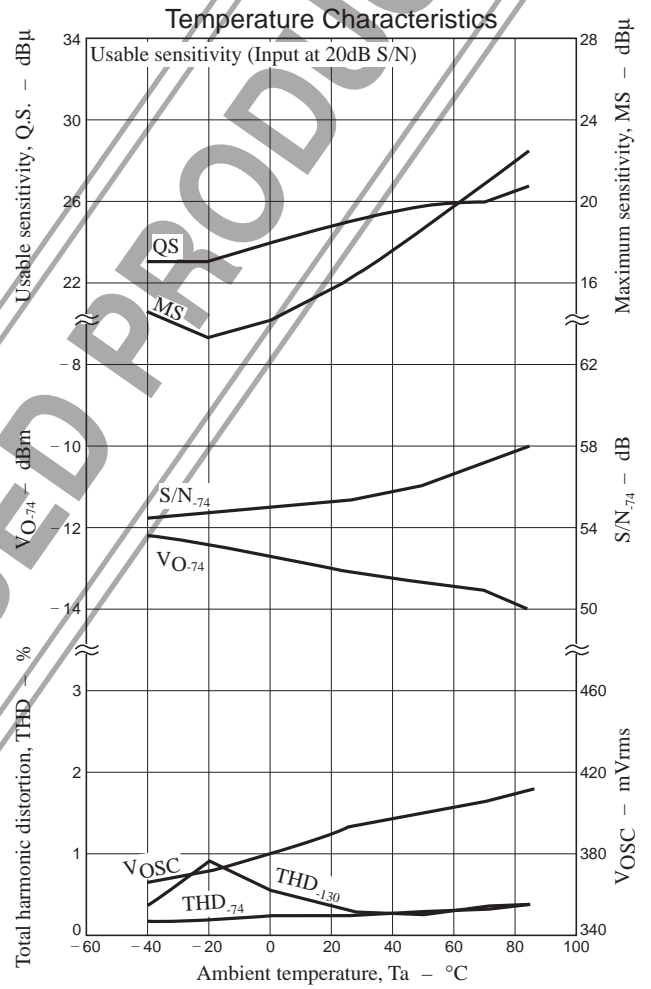
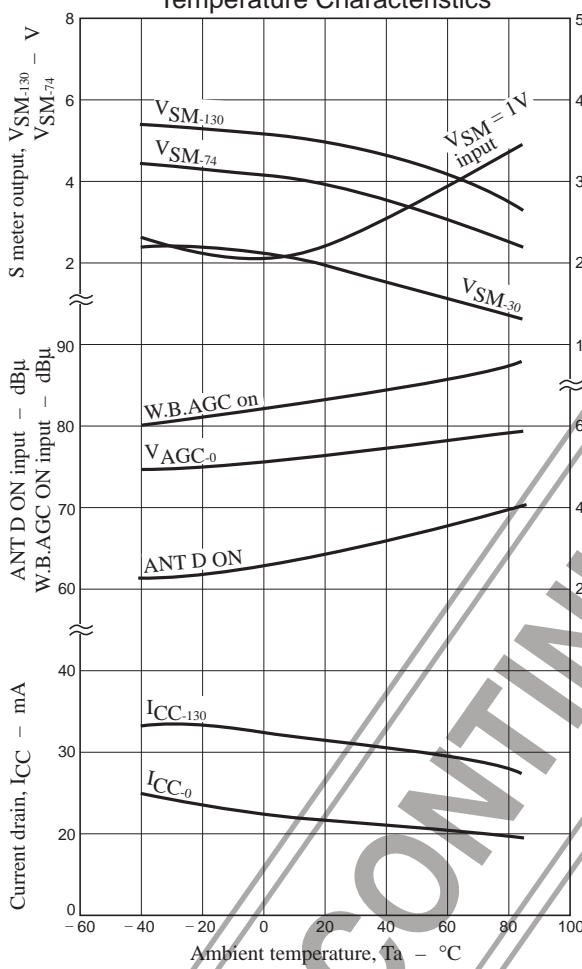
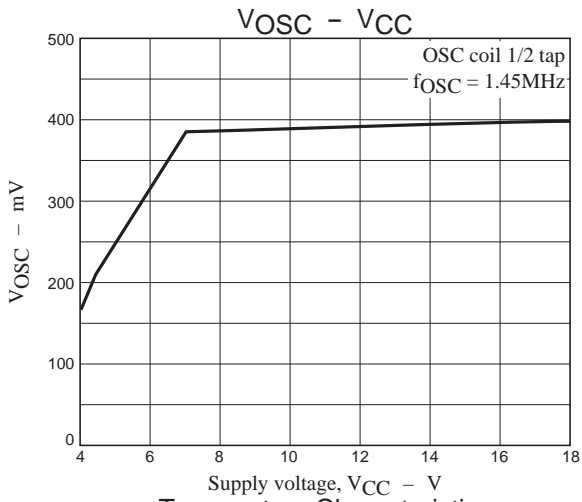


Detection Output, THD - Modulation Characteristics

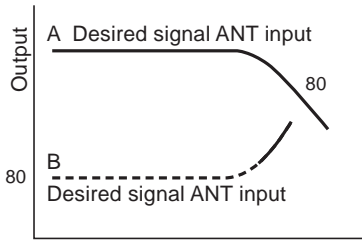
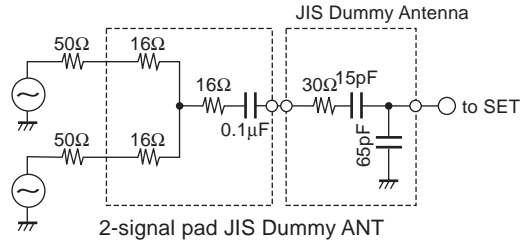




LA1135, 1135M



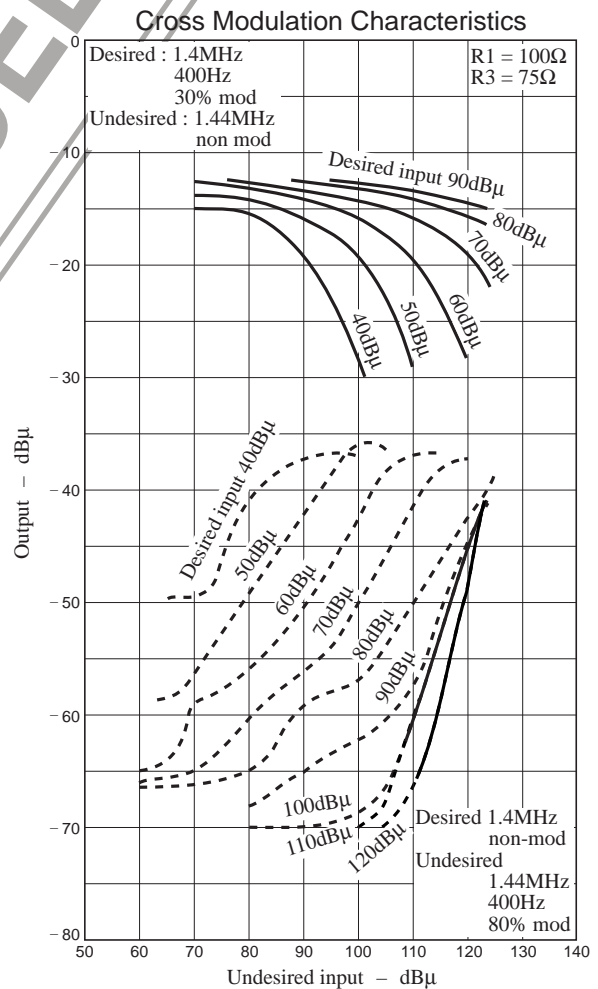
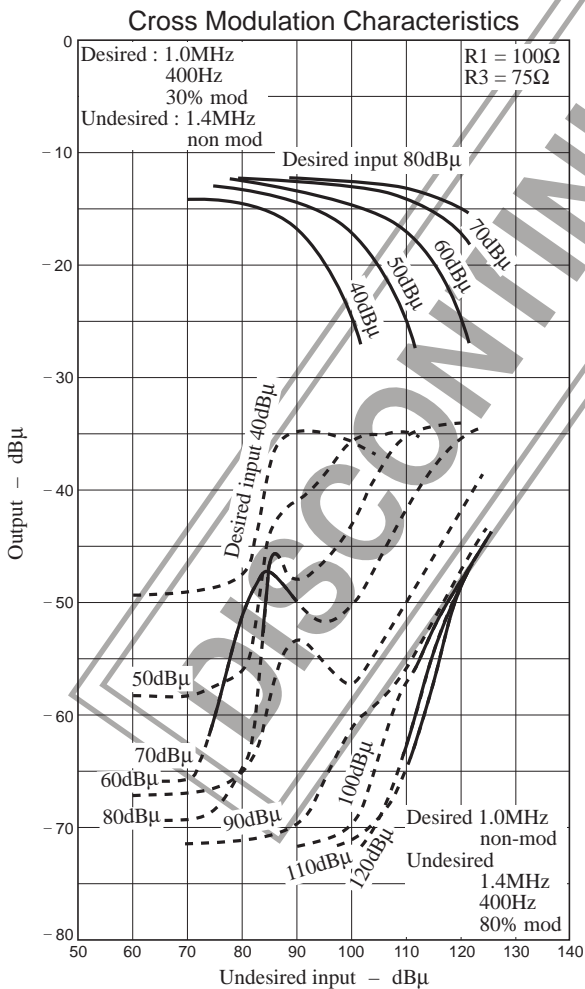
Cross Modulation Characteristics Testing Method



Solid line — Interference
Dotted line - - - - - No interference

A : Desired signal 80dBμ 400Hz 30% mod.
The strength of an undesired signal (non-mod) causes the desired signal to be suppressed.

B : Desired signal 80dBμ non-mod.
The strength of an undesired signal (400Hz 80% mod) causes interference to occur.



Specification for LA1135 loop ANT

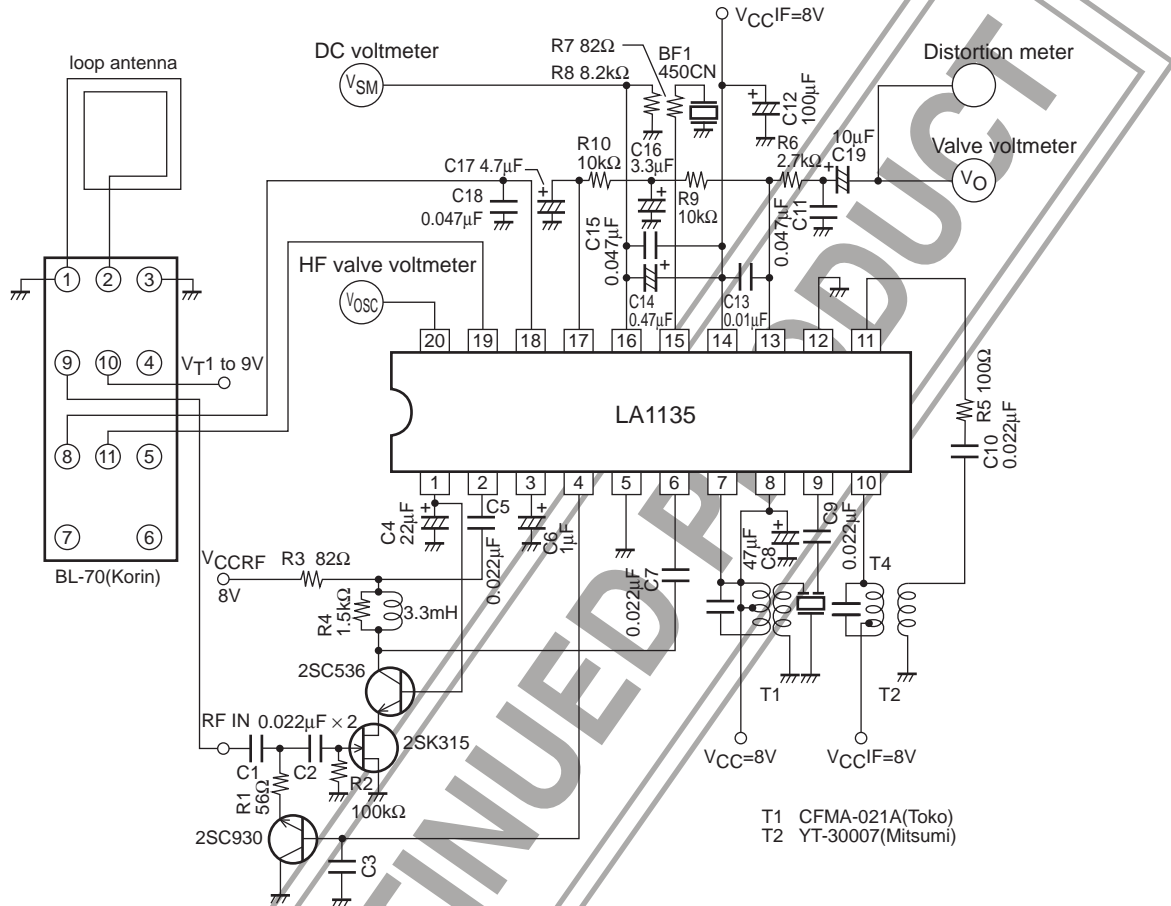
(1) Features of specification for LA1135 loop ANT

1) Excellent high-input characteristic

The antenna damping circuit prevents the antenna circuit from being magnetic-saturated, which results in worsened characteristic, at a high input.

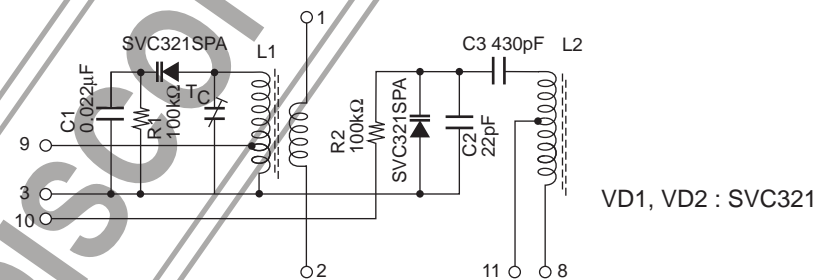
2) Excellent cross modulation characteristic

(2) Application circuit

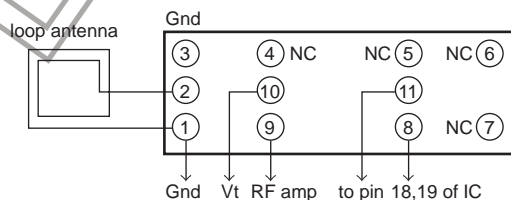


(3) Circuit configuration and connection

3-1 Circuit configuration



3-2 Connection (bottom view)



LA1135, 1135M

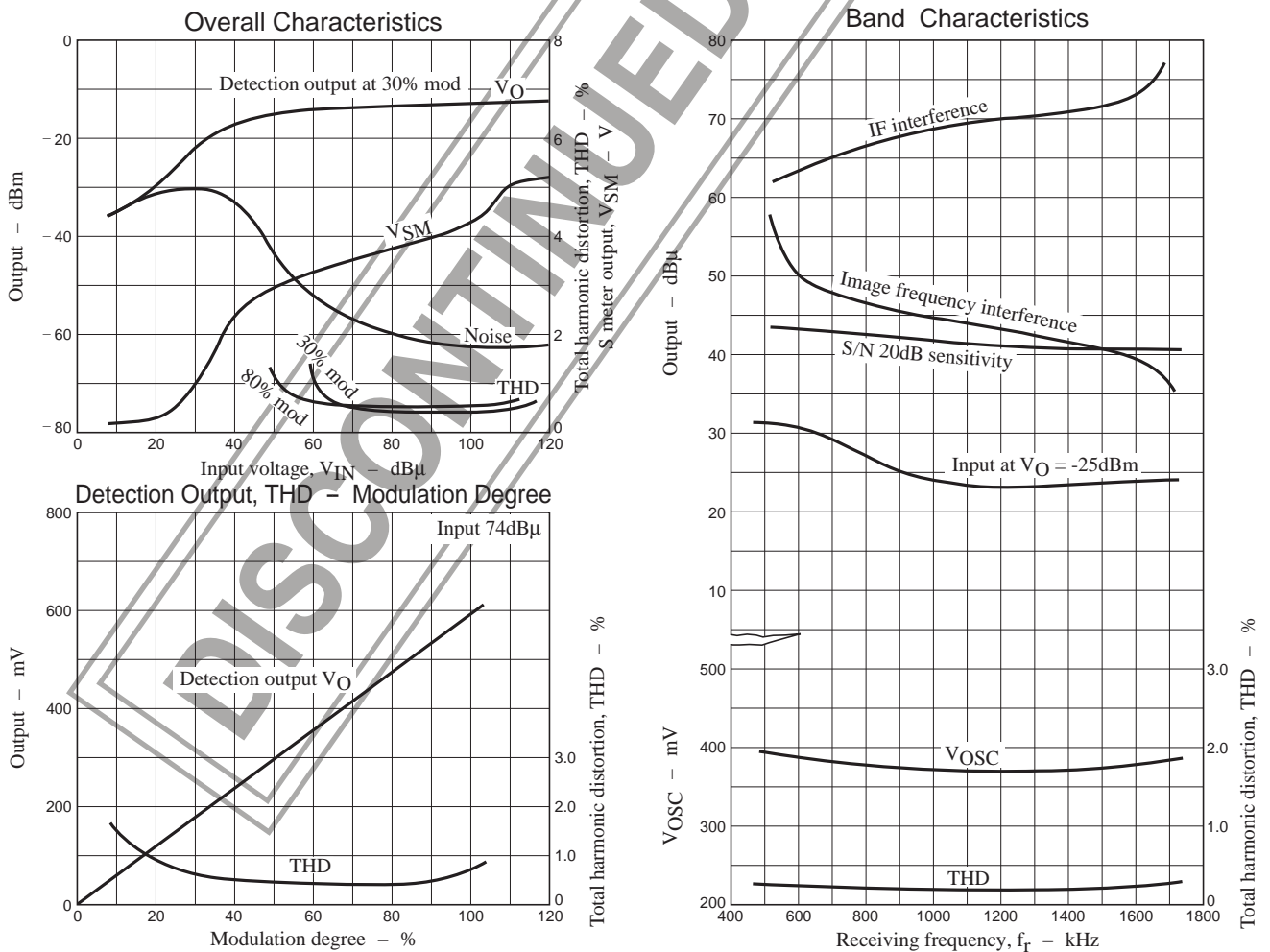
3-3 Pin name

Pin No.	Pin Name
1	Loop ANT
2	Loop ANT
3	RF AMP GND side
4	NC
5	NC

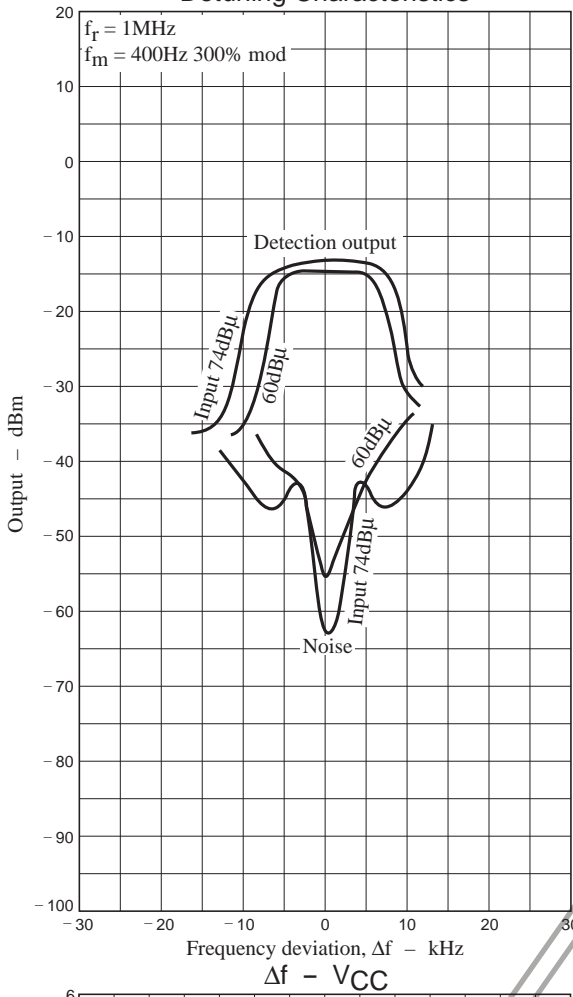
Pin No.	Pin Name
6	NC
7	NC
8	Local OSC
9	RF output
10	Tuning voltage
11	Local OSC

(4) Specification

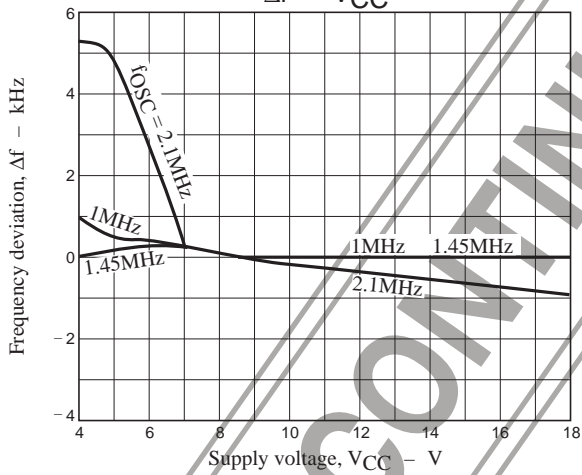
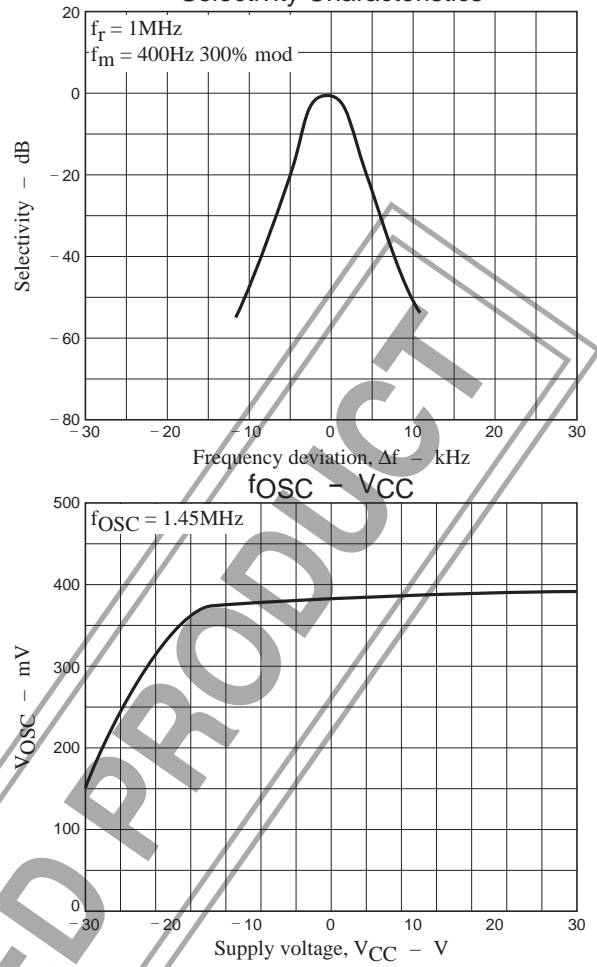
Receiving frequency band	MW BAND
Tuning voltage	1 to 9V
Loop ANT	42579719100 (LA-1500), 4257976000 (LA-100A) (Korin)
IC	LA1135



Detuning Characteristics



Selectivity Characteristics



DISCONTINUED PRODUCT

UNVALUED PRODUCT

- SANYO Semiconductor Co.,Ltd. assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein.
- SANYO Semiconductor Co.,Ltd. strives to supply high-quality high-reliability products, however, any and all semiconductor products fail or malfunction with some probability. It is possible that these probabilistic failures or malfunction could give rise to accidents or events that could endanger human lives, trouble that could give rise to smoke or fire, or accidents that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor Co.,Ltd. products described or contained herein are controlled under any of applicable local export control laws and regulations, such products may require the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written consent of SANYO Semiconductor Co.,Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor Co.,Ltd. product that you intend to use.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production.
- Upon using the technical information or products described herein, neither warranty nor license shall be granted with regard to intellectual property rights or any other rights of SANYO Semiconductor Co.,Ltd. or any third party. SANYO Semiconductor Co.,Ltd. shall not be liable for any claim or suits with regard to a third party's intellectual property rights which has resulted from the use of the technical information and products mentioned above.

This catalog provides information as of August, 2008. Specifications and information herein are subject to change without notice.